

	MT47H128M8SH-25E:M
	Hersteller-Teilenummer: MT47H128M8SH-25E:M
	Hersteller / Marke: Micron Technology
	Teil der Beschreibung: IC SDRAM 1GBIT 400MHZ 60FBGA
Datenblätter:  MT47H128M8SH-25E:M.pdf	RoHs Status: Bleifrei / RoHS-konform
Lagerzustand: New original, 2573 pcs Stock Available.	Liefern von: Hong Kong
Image may be representation. See specs for product details.	Versandweg: DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	MT47H128M8SH-25E:M
Hersteller	Micron Technology
Beschreibung	IC SDRAM 1GBIT 400MHZ 60FBGA
Kategorie	Integrierte Schaltungen (ICs) > Erinnerung
Teilstatus	2573 pcs Stock
Serie	-
Betriebstemperatur	0°C ~ 85°C (TC)
Schnittstelle	Parallel
Verpackung / Gehäuse	60-TFBGA
Supplier Device-Gehäuse	60-FBGA (8x10)
Spannungsversorgung	1.7 V ~ 1.9 V
Speichertyp	Volatile
Geschwindigkeit	400MHz
Speichergröße	1Gb (128M x 8)
Speicherformat	DRAM
Verpackung	Bulk

















































MT47H128M8SH-25E:M ist neu im Original, Suche MT47H128M8SH-25E:M Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie MT47H128M8SH-25E:M Micron Technology mit Garantie und Vertrauen. Anfrage MT47H128M8SH-25E:M: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>MT47H16M16BG-3 IT:B TR Micron Technology IC SDRAM 256MBIT 333MHZ 84FBGA</p>	 <p>MT47H16M16BG-3 IT:B Micron Technology MT47H16M16BG-3 IT:B MICRON</p>	 <p>MT47H128M8SH-187E:M Micron Technology IC SDRAM 1GBIT 533MHZ 60FBGA</p>	 <p>MT47H128M8SH-25E AIT:M Micron Technology IC SDRAM 1GBIT 400MHZ 60FBGA</p>
 <p>MT47H16M16BG-28G MICRON MT47H16M16BG-28G MICRON</p>	 <p>MT47H16M16BG-37E Micron Technology MT47H16M16BG-37E Micron</p>	 <p>MT47H128M8SH-187E:M TR Micron Technology IC SDRAM 1GBIT 533MHZ 60FBGA</p>	 <p>MT47H128M8SH-25E IT:M Micron Technology IC SDRAM 1GBIT 400MHZ 60FBGA</p>

heiße Teile

Mehr

 MT46V8M16P-75Z:D	 MT46V8M16TG-6G	 MT46V8M16TG-6T	 MT46V8M16TG-75	 MT46V8M16TG-75:D
 MT46V8M16TG-75D	 MT47H128M16HG-3:A	 MT47H128M16RT-187E:C	 MT47H128M16RT-25E:C	 MT47H128M16RT-25EIT:C
 MT47H128M16RT-3:C	 MT47H128M4B6-25E:D	 MT47H128M4B6-37E:D	 MT47H128M4B6-3:D	 MT47H128M4B6-5E:D
 MT47H128M4CF-3:F	 MT47H128M8CF-25:H	 MT47H128M8CF-25E:H	 MT47H128M8CF-25EIT:H	 MT47H128M8CF-3:H
 MT47H128M8CF-3:H	 MT47H128M8CF-3IT:H	 MT47H128M8HQ-187E	 MT47H128M8HQ-25E:G	 MT47H128M8QTM-25:J
 MT47H128M8SH-25EIT:M	 MT47H16M16BG-3:B	 MT47H16M16BG-5E:B	 MT47H256M8THN-25E:H	 MT47H256M8THN-3:H
 MT47H32M16BN-37E:D	 MT47H32M16BN-3:D	 MT47H32M16FN-37E:IT	 MT47H32M16HR-25E:G	 MT47H32M16HR-25EAAT:G
 MT47H32M16HR-25EAIT:G	 MT47H32M16HR-25EIT:F	 MT47H32M16HR-25EIT:G	 MT47H32M16HR-25EL:G	 MT47H32M16HR-3:F
 MT47H32M16HR-3:G	 MT47H32M16HR-3IT:F	 MT47H32M16HR-3L:F	 MT47H32M16HW-3:F	 MT47H32M16NF-25E
 MT47H32M16NF-25E:H	 MT47H32M16NF-25EIT:H	 MT47H32M8BP-5E:B	 MT47H64M16HR-25:E	 MT47H64M16HR-25:G

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